DECLARATION FOR NON-PROVISIONAL PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below at 201 et seq. beneath my name.

I believe I am the original, first and sole inventor if only one name is listed at 201 below, or an original, first and joint inventor if plural names are listed at 201 et seq. below, of the subject matter which is claimed and for which a patent is sought on the invention entitled

WAFER WITH A RELAXED USEFUL LAYER AND METHOD OF FORMING THE WAFER

and for which a patent application is attached hereto.

I hereby state that I have reviewed and understand the contents of the above identified application, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

EARLIEST FOREIGN APPLICATION(S), IF ANY, FILED PRIOR TO THE FILING DATE OF THE APPLICATION					
APPLICATION NUMBER	COUNTRY	DATE OF FILING (day, month, year)	PRIORITY CLAIMED		
0211543	France	18 September 2002	Ø YES	□ NO	
			□ YES	□ NO	

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below.

PROVISIONAL APPLICATION NUMBER	FILING DATE
60/439,428	13 January 2003

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code § 112, I acknowledge the duty to disclose information known to me which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

NON-PROVISIONAL	FILING DATE	STATUS			
APPLICATION NO.	FILING DATE	PATENTED	PENDING	ABANDONED	
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i l		1	1	1	

^{*} for use only when the application is assigned to a company, partnership or other organization.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

	statements may jeopa			LAUDDIENING	
	FULL NAME OF	LAST NAME	FIRST NAME	MIDDLE NAME	
2	INVENTOR	AKATSU	Takeshi STATE OR FOREIGN COUNTRY	- COUNTRY OF OTHER	
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	SIGNATURE OF INVENTOR 201		O96963		
	FULL NAME OF	LAST NAME	FIRST NAME	MIDDLE NAME	
!	INVENTOR	GHYSELEN	Bruno	}	
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)	CITIZENSHIP	Seyssinet	France	France	
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ı		SIGNATURE OF INVENTOR 202,		DATE	<u> </u>
				096563	
2	FULL NAME OF INVENTOR	LAST NAME	FIRST NAME	MIDDLE NAME	
)	RESIDENCE & CITIZENSHIP	СІТУ	STATE OR FOREIGN COUNTRY	COUNTRY OF CITIZENSHIP	
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1		SIGNATURE OF INVENTOR 203		DATE	
2	FULL NAME OF INVENTOR	LAST NAME	FIRST NAME	MIDDLE NAME	
0	RESIDENCE & CITIZENSHIP	СІТУ	STATE OR FOREIGN COUNTRY	COUNTRY OF CITIZENSHIP	
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		SIGNATURE OF INVENTOR 204		DATE	
 2	FULL NAME OF INVENTOR	LAST NAME	FIRST NAME	MIDDLE NAME	
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5	POST OFFICE ADDRESS	STREET	CITY	STATE OR COUNTRY	ZIP CODE
					

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Takeshi AKATSU et al.	Confirmation No.:
Application No.:	Group Art Unit:
Filing Date: Concurrently herewith	Examiner:
For: WAFER WITH A RELAXED USEFUL LAYER AND METHOD OF FORMING THE WAFER	Attorney Docket No.: 4717-8900

POWER OF ATTORNEY BY ASSIGNEE AND EXCLUSION OF INVENTOR(S) UNDER 37 C.F.R. 3.71

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The undersigned assignee of the entire interest in the above-identified subject application hereby appoints Allan A. Fanucci (Reg. No. 30,256) and Daniel J. Hulseberg (Reg. No. 36,554) of WINSTON & STRAWN LLP (Customer No. 28,765) to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith.

Please direct all correspondence for this application to Customer No. 28765 to the attention of Allan A. Fanucci (telephone 212-294-3311, facsimile 212-294-4700).

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An	assignment of the en	tire interest in the al	oove-identif	ied subject applicat	ion:
	is submitted herewith for recording and a copy is attached.				
	was submitted for	mitted for recordation on		and a copy is attached.	
	was recorded on		_ at Reel	, Frame	·
The	undersigned has rev	iewed this assignme	ent and, to th	ne best of his/her kr	owledge,
title is in th	e assignee seeking to	take action in this	application a	and that he/she is en	npowered
to act on it	s behalf.				
ASSIGNE	E: S.O.I. TI	EC SILICON ON I	NSULATO	R TECHNOLOG	IES S.A.
Signature:	- H	lev_			
Date of Sig	gnature: 09 (2263		·	
Typed Nar	ne: <u>Emmanu</u>	el Huyghe	·		
Position/T	tle: <u>Intellectu</u>	al Property Manage	r		
Address:	Parc Tecl	hnologique des Font	taines		
	38926 Be	ernin France			